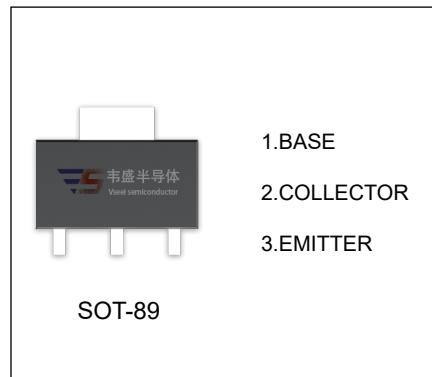


KTA1273 TRANSISTOR (PNP)

FEATURES

- High Current
- Low Voltage
- Complementary to KTC3205



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-Base Voltage	-30	V
V_{CEO}	Collector-Emitter Voltage	-30	V
V_{EBO}	Emitter-Base Voltage	-5	V
I_c	Collector Current	-2	A
P_c	Collector Power Dissipation	500	mW
$R_{\theta JA}$	Thermal Resistance From Junction To Ambient	250	°C/W
T_J, T_{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-1\text{mA}, I_B=0$	-30			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-30			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-1\text{mA}, I_C=0$	-5			V
Collector cut-off current	I_{CBO}	$V_{CB}=-30\text{V}, I_E=0$			-100	nA
Emitter cut-off current	I_{EBO}	$V_{EB}=-5\text{V}, I_C=0$			-100	nA
DC current gain	h_{FE}	$V_{CE}=-2\text{V}, I_C=-0.5\text{A}$	100		320	
Collector-emitter saturation voltage	$V_{CE(\text{sat})}$	$I_C=-1.5\text{A}, I_B=-30\text{mA}$			-2	V
Base-emitter voltage	V_{BE}	$V_{CE}=-2\text{V}, I_C=-500\text{mA}$			-1	V
Transition frequency	f_T	$V_{CE}=-2\text{V}, I_C=-500\text{mA}$		120		MHz
Collector output capacitance	C_{ob}	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$		48		pF

CLASSIFICATION OF h_{FE}

RANK	O	Y
RANGE	100 ~ 200	160 ~ 320
MARKING	1273	